## NSN 5961-01-116-4490

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-116-4490 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.300 inches Overall Diameter: Between 0.370 inches and 0.380 inches **End Application:** An/arc-190 13499 fscm **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage/static/emitter open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-8529 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**